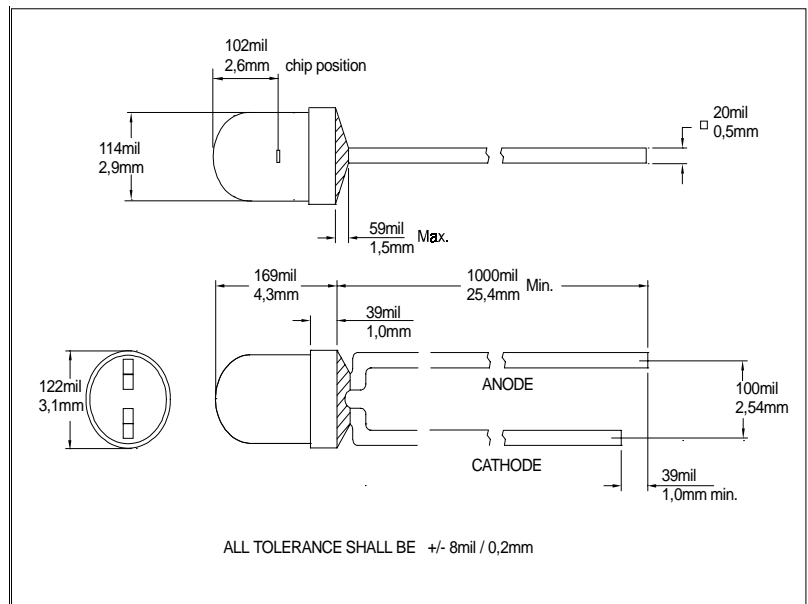


Infrared Light Emitting Diode IRED 870nm/20ns/30° FQT5501

Features

- * Standard design LED for general purpose
Based on double hetero structure of GaAIAs
- * Fast switching time : typical <20ns
- * High cut-off frequency of >20Mhz @-3dB
- * High power for T1 case with 30° full angle
- * Water-clear package style without stand-off
- * Application : Open-Air communication / IrDa
IR-Flash-Lights
Medical instruments
Light interrupter and switches



Electrical and optical characteristics and absolute maximum ratings (Ta=25°C unless otherwise noted)

Symbol	Parameter	MIN	Typ	MAX	Unit	Test conditions
I _F	DC Forward current			100	mA	
I _{PEAK}	Peak Forward current			1500	mA	T _p < 10μsec. ; T=1:100 ; R _{therm} < 100 K/W
V _F	Forward Voltage	1,3	1,5	2,1	V	I _F = 50mA
V _R	Reverse Voltage	5			V	I _{rev} = 100μA
λ _{Peak}	Peak Wavelength	860	870	885	nm	I _F = 50mA
Δλ _{0,5}	Bandwidth of half power	25	30		nm	I _F = 50mA
t _f	Fall time	10	18		ns	I _F = 100mA
t _r	Rise time	10	20		ns	I _F = 100mA
F _E	Total Power Output	20	26		mW	I _F = 100mA
I _E	Radiant Intensity	95	160		mW/sr	I _F = 100mA
D	Diameter of light emitting point		2,3		mm	I _F = 20mA, 63% of radiant output (IEC825)
A	Chip size		0,13		mm ²	Chip size : 360μmX360μm
2Φ _{0,5}	Emission Angel	25	30	35	deg.	Φ _E = 50%
TK _{VF}	Temp.Coeff. of Forward Voltage		- 2		mV/K	
TK _F	Temp.Coeff. of Radiant Power		- 0,4		%/K	
T _{Operating}	Operating Temperature	- 25		85	°C	
T _{Storage}	Storage Temperature	- 25		85	°C	
T _{Soldering}	Soldering Temperature			260	°C	2mm from case @5 sec.
Θ _{j-PIN}	Thermal Resistance		450		K/W	
P _{tot}	Total Power Dissipation			210	mW	derate above 45°C 2,5mW/K

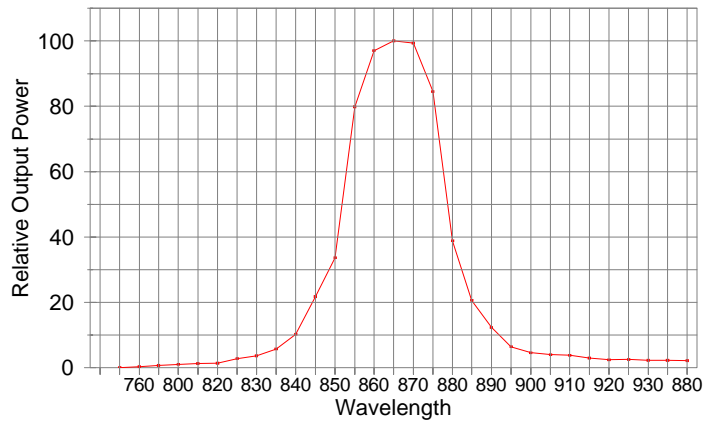
Order Informations :

FQT5501 Bulk
FQT5501TR Taped on Reel / 2000 pcs. standard reel
FQT5501TA Taped in AMMOPACK

Fietje reserves the right to make changes at any time in order to improve design and to supply the best product possible, contact Fietje for latest device specification sheets before using.

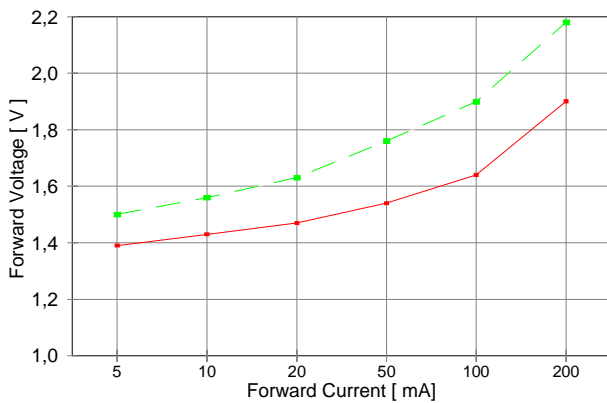
Infrared Light Emitting Diode IRED 870nm/20ns/30° FQT5501

Relativ Spectral Emission

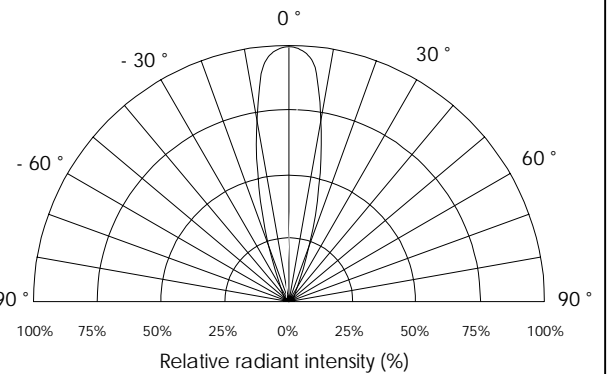


Forward Voltage

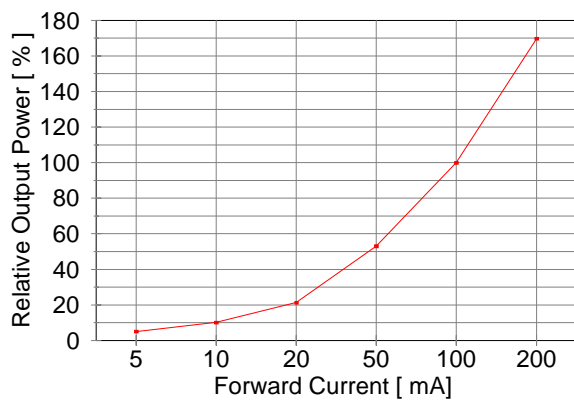
$V_f = f(I_f)$ typ.



Angular Displacement [degree]



Relative Output Power (typ.)



Relative Radiant Output Power (typ.)

